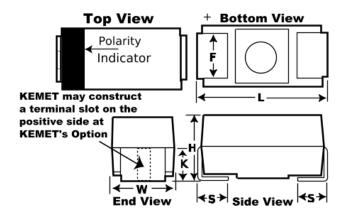


T510X108M004ZTE035

Obsolete

B45396R, Tantalum, MnO2 Tantalum, Multi-Anode, 1,000 uF, 20%, 4 VDC, SMD, Molded, Ultra Low ESR, 35 mOhms, 7343, Height Max = 4.4mm



General Information		
Series	B45396R	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, Ultra Low ESR	
Features	Ultra Low ESR	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Notes	Obsolete. Old Part Number [Obsolete] Was B45396R0108M599.	

Dimensions		
Footprint	7343	
L	7.3mm +/-0.3mm	
W	4.3mm +/-0.3mm	
Н	4.1mm +/-0.3mm	
S	1.3mm +/-0.3mm	
F	2.4mm +/-0.1mm	
K	1.8mm TYP	

Specifications	
Capacitance	1,000 uF
Capacitance Tolerance	20%
Voltage DC	4 VDC (85C), 2.68 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
Resistance	0.035 Ohms (100kHz)
Ripple Current	2800 mAmps (25C), 2520 mAmps (85C), 1120 mAmps (125C)
Leakage Current	40 uA

Packaging Specifications			
Packaging	T&R, 178mm		
Packaging Quantity	400		